

L Number	Hits	Search Text	DB	Time stamp
1	320	semiconductor and (complementary adj bipolar adj transistor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/10 13:03
2	140	(semiconductor and (complementary adj bipolar adj transistor)) and electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/10 13:03
3	128	((semiconductor and (complementary adj bipolar adj transistor)) and electrode) and emitter and base and collector	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/10 13:04
4	81	((semiconductor and (complementary adj bipolar adj transistor)) and electrode) and emitter and base and collector) and ((polycrystal\$4 adj (silicon or si)) or polysilicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/10 13:04